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- Members of the Texas Instruments
 Widebus™ Family
- Translate Between GTL Logic Levels and LVTTL or 5-V TTL Logic Levels
- Support Mixed-Mode Signal Operation on A Port
- Universal Bus Transceiver (UBT™)
 Combines D-Type Latches and D-Type
 Flip-Flops With Qualified Storage Enable
- Bus-Hold Data Inputs Eliminate the Need for External Pullup Resistors on A Port
- Flow-Through Architecture Facilitates
 Printed Circuit Board Layout
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Ceramic Flat (WD) Packages

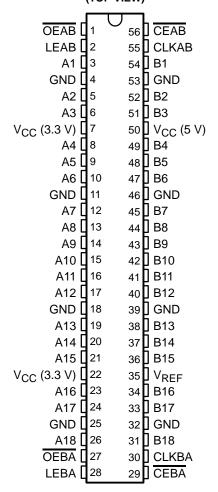
description

These 18-bit bus transceivers combine D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

The B port operates at GTL levels while the A port and control inputs are compatible with LVTTL and 5-V TTL logic levels.

Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock or latch-enable can be controlled by the clock-enable (\overline{CEAB} and \overline{CEBA}) inputs. For A-to-B data flow, the devices operate in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if CEAB is low and CLKAB is held at a high or low logic level. If LEAB is low, the A-bus data is stored in the latch/flip-flop on the low-to-high transition of CLKAB if CEAB is also low. OEAB is active low. When OEAB is low, the outputs are active. When OEAB is high, the outputs are in the high-impedance state. Data flow for B to A is similar to that for A to B, but uses OEBA, LEBA, CLKBA, and CEBA.

SN54GTL16612 . . . WD PACKAGE SN74GTL16612 . . . DGG OR DL PACKAGE (TOP VIEW)





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description (continued)

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54GTL16612 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74GTL16612 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE†

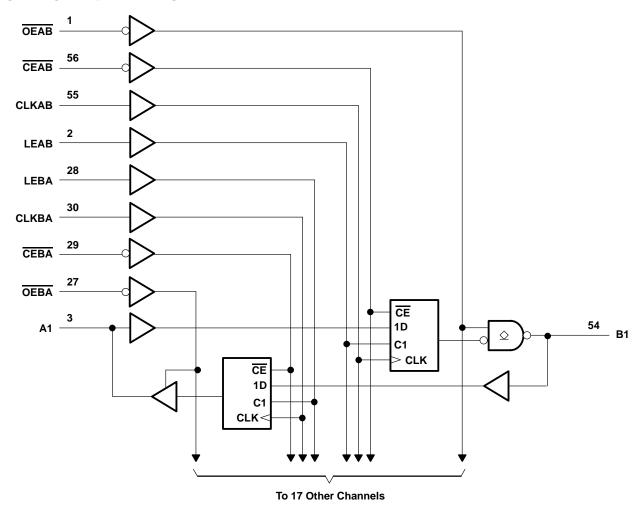
		INPUTS		OUTPUT	MODE	
CEAB	OEAB	LEAB	CLKAB	Α	В	MODE
Х	Н	Х	Х	Х	Z	
L	L	L	Н	Χ	в ₀ ‡	Latched storage of A data
L	L	L	L	Χ	в ₀ §	
Х	L	Н	Х	L	L	Transparent
Х	L	Н	Χ	Н	Н	Transparent
L	L	L	1	L	L	Clasked starons of A data
L	L	L	\uparrow	Н	Н	Clocked storage of A data
Н	L	L	Х	Χ	B ₀ §	Clock inhibit

[†] A-to-B data flow is shown: B-to-A data flow is similar but uses OEBA, LEBA, CLKBA, and CEBA.

[‡] Output level before the indicated steady-state input conditions were established, provided that CLKAB was high before LEAB went low

[§] Output level before the indicated steady-state input conditions were established

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC} : 3.3 V	–0.5 V to 4.6 V
5 V	
Input voltage range, V _I (see Note 1): A port	–0.5 V to 7 V
B port	–0.5 V to 4.6 V
Voltage range applied to any output in the high or power-off state, V _O (see Note 1): A	port0.5 V to 7 V
В	port0.5 V to 4.6 V
Current into any output in the low state, I _O : A port	128 mA
B port	80 mA
Current into any A-port output in the high state, IO (see Note 2)	64 mA
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	
Package thermal impedance, θ_{JA} (see Note 3): DGG package	81°C/W
DL package	74°C/W
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

			SN54GTL16612			SN				
			MIN	NOM	MAX	SN74GTL16612 MIN NOM MAX			UNIT	
VCC	Supply voltage	3.3 V	3.15	3.3	3.45	3.15	3.3	3.45	`,,	
		5 V	4.75	5	5.25	4.75	5	5.25	V	
VREF	Supply voltage	•		0.8			0.8		V	
١/،	lanut valtara	B port			V _{CC} (3.3 V)			V _{CC} (3.3 V)	V	
۷į	Input voltage	Except B port			5.5			5.5	V	
.,	High-level	B port	V _{REF} +50 mV			V _{REF} +50 mV			V	
VIH	input voltage	Except B port	2			2			V	
\/	Low-level	B port			V _{REF} -50 mV			V _{REF} -50 mV	V	
VIL	input voltage	Except B port			0.8			0.8	٧	
ΙK	Input clamp curre	nt			-18			-18	mA	
ІОН	High-level output current	A port			-32			-32	mA	
	Low-level	A port			64			64	mA	
lOL	output current	B port			40			40	IIIA	
TA	Operating free-air	temperature	– 55		125	-40		85	°C	

NOTE 4: Unused control inputs must be held high or low to prevent them from floating.



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electrical characteristics over recommended operating free-air temperature range, V_{REF} = 0.8 V (unless otherwise noted)

PARAMETER		TEGT COMPL	SN54	GTL166	12	SN740	LINUT				
		TEST CONDI	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT		
VIK		V _{CC} (3.3 V) = 3.15 V, V _{CC} (5 V) = 4.75 V	I _I = -18 mA			-1.2			-1.2	V	
		$V_{CC} = MIN \text{ to } MAX^{\ddagger},$	I _{OH} = -100 μA	V _{CC} -0.2			V _{CC} -0.2				
VOH	A port	V_{CC} (3.3 V) = 3.15 V,	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V	
		V _{CC} (5 V) = 4.75 V	$I_{OH} = -32 \text{ mA}$	2			2				
			$I_{OL} = 100 \mu\text{A}$			0.2			0.2		
	A port	V_{CC} (3.3 V) = 3.15 V,	$I_{OL} = 16 \text{ mA}$			0.4			0.4		
VOL	Triport	V_{CC} (5 V) = 4.75 V	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V	
·OL			$I_{OL} = 64 \text{ mA}$			0.6			0.55		
	B port	V_{CC} (3.3 V) = 3.15 V, V_{CC} (5 I_{OL} = 40 mA	5 V) = 4.75 V,			0.5	2 0.2 0.2 0.4 0.4 0.5 0.5 0.6 0.55 0.5 0.4 10 10 1000 20 1 1 -30 -30 5 5 -5 -5 1000 100 75 -75 1 1 10 10 -1 -1 -10 -10 1 1 5 5 5 5				
	Control inputs	$V_{CC} = 0$ or MAX^{\ddagger} ,	V _I = 5.5 V			10			10		
			V _I = 5.5 V			1000			20		
l _l	A port	V_{CC} (3.3 V) = 3.45 V, V_{CC} (5 V) = 5.25 V	VI = VCC			1			1	μΑ	
•		VCC (3 V) = 5.25 V	V _I = 0			-30			-30		
	B port	V _{CC} (3.3 V) = 3.45 V,	$V_{I} = V_{CC} (3.3 \text{ V})$			5			5		
	Б роп	V _{CC} (5 V) = 5.25 V	V _I = 0			- 5			- 5		
l _{off}		$V_{CC} = 0$, V_{I} or $V_{O} = 0$ to 4.5			1000			100	μΑ		
liza - i -is	A port	V_{CC} (3.3 V) = 3.15 V,	V _I = 0.8 V	75			75			μΑ	
l(hold)	A port	V _{CC} (5 V) = 4.75 V	V _I = 2 V	-75			-75			μΑ	
l	A port	V_{CC} (3.3 V) = 3.45 V, V_{CC} (5 V_{O} = 3 V	5 V) = 5.25 V,			1			1		
lozh	B port	V_{CC} (3.3 V) = 3.45 V, V_{CC} (5 V_{O} = 1.2 V	5 V) = 5.25 V,			10			10	μΑ	
	A port	V _{CC} (3.3 V) = 3.45 V, V _{CC} (5 V _O = 0.5 V	5 V) = 5.25 V,			-1			-1		
lozL	B port	V _{CC} (3.3 V) = 3.45 V, V _{CC} (5 V _O = 0.4 V	5 V) = 5.25 V,			-10			-10	μΑ	
_		V _{CC} (3.3 V) = 3.45 V,	Outputs high			1			1		
(3.3 V)	A or B port	V_{CC} (5 V) = 5.25 V, I_{O} = 0,	Outputs low			5			5	mA	
(0.0 V)	Port	$V_I = V_{CC}$ (3.3 V) or GND	Outputs disabled			1			1		
		V _{CC} (3.3 V) = 3.45 V,	Outputs high			120			120		
I _{CC} (5 V)	A or B port	V_{CC} (5 V) = 5.25 V, I_{O} = 0,	Outputs low			120			120	mA	
(5 1)	Port	$V_I = V_{CC}$ (3.3 V) or GND	Outputs disabled			120			120		
ΔICC§		V_{CC} (3.3 V) = 3.45 V, V_{CC} (5 A or control inputs at V_{CC} (3. One input at 2.7 V				1			1	mA	
Ci	Control inputs	V _I = 3.15 V or 0			3.5	12		3.5		pF	
Cı	A port	V _O = 3.15 V or 0			12	18		12		r.	
Cio	B port	Per IEEE Std 1194.1				10			5	pF	

[§] This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.



[†] All typical values are at V_{CC} (3.3 V) = 3.3 V, V_{CC} (5 V) = 5 V, T_A = 25°C. ‡ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

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timing requirements over recommended ranges of supply voltage and operating free-air temperature, $V_{REF} = 0.8 \text{ V}$ (unless otherwise noted)

			SN54GTI	_16612	SN74GTL	UNIT			
			MIN	MAX	MIN	MAX	UNII		
f _{clock}	Clock frequency		0	95	0	95	MHz		
	Pulse duration	LEAB or LEBA high	3.3		3.3		20		
t _W	ruise duration	CLKAB or CLKBA high or low	5.6		5.6		ns		
		A before CLKAB↑	1.2		0				
		B before CLKBA↑	3.4		2.5		ns		
	Setup time	A before LEAB↓	1.2		0.4				
t _{su}		B before LEBA↓	1		0.9				
		CEAB before CLKAB↑	2.1		1				
		CEBA before CLKBA↑	2.6		2.1		1		
		A after CLKAB↑	2.9		2.7				
		B after CLKBA↑	4.1		0.4				
	l lald time	A after LEAB↓	4.5		3.4				
th	Hold time	B after LEBA↓	4.3		3.3		ns		
		CEAB after CLKAB↑	2		1.5				
		CEBA after CLKBA↑	1		0.4				

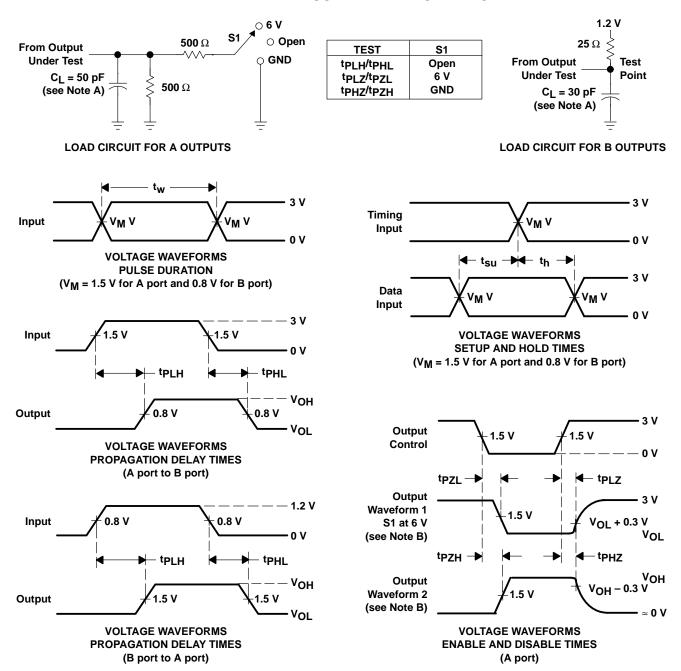
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $V_{REF} = 0.8 \text{ V}$ (see Figure 1)

DADAMETED	FROM	то	SN	SN54GTL16612			SN74GTL16612		
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT
f _{max}			95			95			MHz
t _{PLH}	А	В	1	2.6	4.5	1	2.6	3.8	ns
t _{PHL}	Λ	В	1	2.2	4.5	1	2.2	4	115
t _{PLH}	LEAB	В	1	3.6	5.5	1.8	3.6	5.4	ns
^t PHL	LEAB	В	1	3.3	6	1.5	3.3	5.5	115
t _{PLH}	CLKAB	В	1	3.7	5.5	1.8	3.7	5.3	ns
t _{PHL}	CLKAB	В	1	3.3	5.5	1.5	3.3	5.5	115
^t PLH	OEAB	В	1	3.3	5.5	1.6	3.3	4.7	ns
^t PHL	OEAB	В	1	3.2	5.5	1.3	3.2	5.5	
t _r	Transition time, B or	utputs (0.5 V to 1 V)		1.3			1.3		ns
t _f	Transition time, B or	utputs (1 V to 0.5 V)		0.5			0.5		ns
^t PLH	В	А	2	4.8	6.9	2	4.8	6.9	ns
^t PHL	В	A	1	3.6	5.1	1.4	3.6	5.1	115
^t PLH	LEBA	А	2	4.3	6.1	2.1	4.3	6.1	ns
t _{PHL}	LLBA	A	1	3.6	5.1	1.9	3.6	5.1	115
^t PLH	CLKBA	А	2	4.5	6.4	2.3	4.5	6.4	ns
t _{PHL}	CLNDA		2	4	5.6	2.2	4	5.6	115
t _{en}	 OEBA	А	1	4.7	7.5	1.9	4.7	7.2	ns
^t dis	OLBA	A	2	4.6	6.9	2.5	4.6	6.9	115

[†] All typical values are at V_{CC} (3.3 V) = 3.3 V, V_{CC} (5 V) = 5 V, T_A = 25°C.



PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms



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